

# isc N-Channel MOSFET Transistor

## AOTF8N65

#### FEATURES

- Drain Current –I\_D= 8A@ T\_C=25 $^\circ\!\!\mathbb{C}$
- Drain Source Voltage-: V<sub>DSS</sub>= 650V(Min)
- Static Drain-Source On-Resistance
- : R<sub>DS(on)</sub> = 1.15 Ω (Max)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### DESCRIPTION

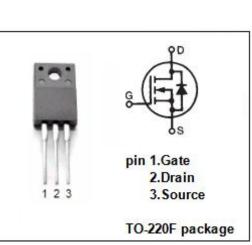
• Designed for use in switch mode power supplies and general purpose applications.

ABSOLUTE WAATWOW RATINGS (Ta=25 C)						
SYMBOL	PARAMETER	VALUE	UNIT			
V <sub>DSS</sub>	Drain-Source Voltage	650	V			
V <sub>GS</sub>	Gate-Source Voltage-Continuous	±30	V			
ID	Drain Current-Continuous	8	A			
I <sub>DM</sub>	Drain Current-Single Pluse	32	A			
P <sub>D</sub>	Total Dissipation @T <sub>c</sub> =25℃	50	W			
TJ	Max. Operating Junction Temperature -55~150		°C			
T <sub>stg</sub>	Storage Temperature -55~150		°C			

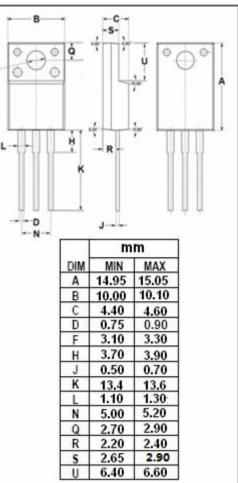
### ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	2.5	°C/W



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### **AOTF8N65**

### **ELECTRICAL CHARACTERISTICS**

#### $T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
V(BR)DSS	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> = 0.25mA	650		V
V <sub>GS</sub> (th)	Gate Threshold Voltage	V <sub>DS</sub> = 5V; I <sub>D</sub> = 0.25mA	3	4.5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> = 4A		1.15	Ω
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> = ±30V;V <sub>DS</sub> =0		±100	nA
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 650V; V <sub>GS</sub> = 0 V <sub>DS</sub> = 520V; V <sub>GS</sub> = 0@T <sub>J</sub> = 55℃		1 10	μA
V <sub>SD</sub>	Forward On-Voltage	I <sub>S</sub> = 1A; V <sub>GS</sub> = 0		1	V

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